









PRODUCT DATASHEET



- ► DC Input Photo Coupler
- ► Standard DIP4
- ➤ Zero-Cross TRIAC

TD308X-4L-GV





TD308X-4L Series

DESCRIPTION:





The TDTD308X-4L series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a monolithic silicon zero-cross photo TRIAC in a plastic DIP4 package with different lead forming options.

With the robust coplanar double mold structure, TD308X-4L series provide the most stable isolation feature.

APPLICATIONS:

- Solenoid/valve controls
- Lighting controls
- Motor controls
- Temperature controls
- Static AC power switches
- Solid state relays
- Interfacing microprocessors to 115 to 240VAC peripherals

FEATURES:

- High isolation 5000Vrms
- DC input with zero-cross photo TRIAC output
- Operating temperature range -40°C to +100°C
- REACH & RoHS compliance; Halogen free
- MSL class 1
- **Regulatory Approvals:**
 - UL UL1577
 - VDE EN60747-5-5 (VDE0884-5)
 - CQC GB4943.1, GB8898
 - cUL CSA Component Acceptance Service Notice 5A

Packing: 100pcs/tube





Release Date: 10 June 2025 Version: A00



NAMING & ORDERING INFORMATION:

Naming Information:

TD308 X - 4L - G V		
TD308	Part Number	
×	Selection: LED Trigger Current (X=1~3)	
4L	DIP4 Based Package	
G	Green Option	
V	VDE Option	

Ordering Information:

TD308X-4L-GV

 \underline{X} = Selection: LED Trigger Current (X=1~3)

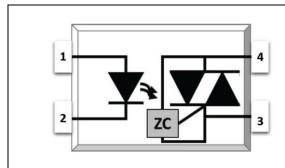
Part Number	Cumbal	Values			Lloit	Tost Condition
Part Number	Symbol	Min.	Тур.	Max.	Unit	Test Condition
TD3081-4L-GV	l _{FT}			15		L =100m A
TD3082-4L-GV				10	mA	I _{TM} =100mA Terminal
TD3083-4L-GV				5		Voltage=3V

Version No.	Original Release Date
Rev: A00	05/09/2024



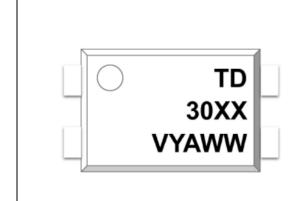
SCHEMATIC DIAGRAM & MARKING:

Schematic Diagram:



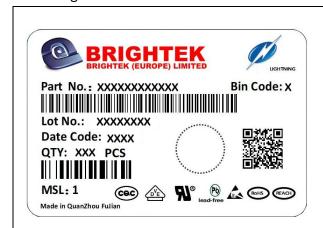
PIN Definition			
1	Anode		
2	Cathode		
3	Terminal		
4	Terminal		

Marking Information:



	Marking Definition
TD	Manufacturer Code
308X	Part Number & Rank
V	VDE Applicable
Υ	Fiscal Year
А	Manufacturing Code
ww	Work Week

Labelling Information:



This product is manufactured, tested, and packed by



for more details, please visit www.tdled.com



ABSOLUTE CHARACTERISTICS:

Absolute Maximum Ratings:

Parameter	Symbol	Ratings	Unit
	INPUT		
Forward Current	lf	60	mA
Reverse Voltage	V _R	6	V
Junction Temperature	Tj	125	°C
Input Power Dissipation	Pı	100	mW
	OUTPUT		
Off-State Output Terminal Voltage	V _{DRM}	800	V
Peak Repetitive Surge Current PW=100μs, 120pps	I _{TSM}	1	А
On-State RMS Current	I _{T(RMS)}	100	mA
Junction Temperature	Tj	125	°C
Output Power Dissipation	Po	300	mW
	COMMON		
Total Power Dissipation	P _{tot}	400	mW
Isolation Voltage	V _{iso}	5000 *1	Vrms
Operating Temperature	Topr	-40~+100	°C
Storage Temperature	T _{stg}	-55~+125	°C
Soldering Temperature	T _{sol}	260 *²	°C

^{*1.} AC for 1 minute, R.H.=40~60%.

^{*2.} For 10 seconds max.



ELECTRICAL CHARACTERISTICS:

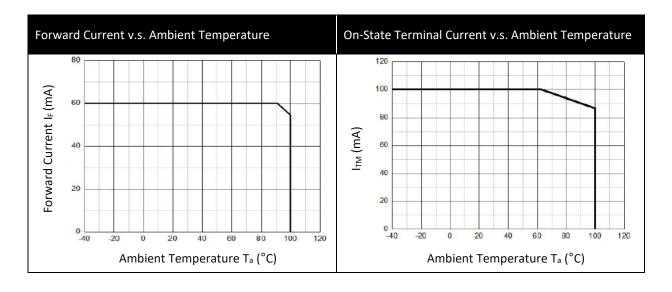
Electrical Optical Characteristics at T_a=25°C:

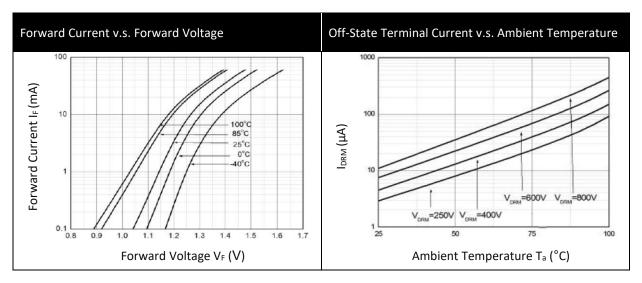
Paramete	er	Symbol		Values		Unit	Test Condition
		'	Min.	Тур.	Max.		
		1	INPU	Γ	1	T	
Forward Voltage		V _F		1.24	1.4	V	I _F =10mA
Reverse Current		I _R			10	μΑ	V _R =6V
Input Capacitance		Cin		8.5	250	pF	V=0, f=1kHz
			OUTPU	JT			
Peak Off-State Curre Either Direction	nt	I _{DRM}			500 *1	nA	V_{DRM} =Rated V_{DRM} I_F =0
Peak Off-State Voltage Either Direction	ge	V_{TM}		1.59	2.5	V	I _{TM} =100mA
Critical Rate of Rise of Voltage	of Off-State	dV/dt	1000			V/µs	V _{PEAK} =400V I _F =0
		TRAN	NSFER CHAR	ACTERISTICS			
LED Trigger Current	TD3081-4L	I _{FT}			15	mA	I _{TM} =100mA Terminal Voltage=3V
	TD3082-4L				10		
	TD3083-4L				5		
Holding Current		Ін		237		μА	
Isolation Resistance		R _{ISO}	10^12	10^14		Ω	DC=500V, 40~60% R.H.
Floating Capacitance		Cıo		0.4	1	pF	V=0, f=1MHz
		ZERO-C	ROSSING CH	ARACTERIST	ICS		
Inhibit Voltage		V _{INH}			20	V	I _F =Rated I _{FT}
Leakage in Inhibited	State	I _{DRM2}			500	μА	I _F =Rated I _{FT} V _{DRM} =Rated V _{DRM}

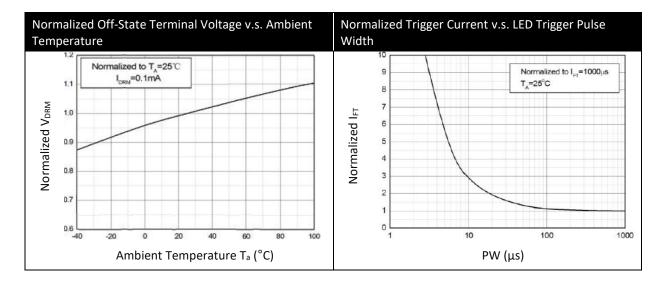
^{*1.} Test voltage must be applied within dV/dt rating.



CHARACTERISTIC CURVES:

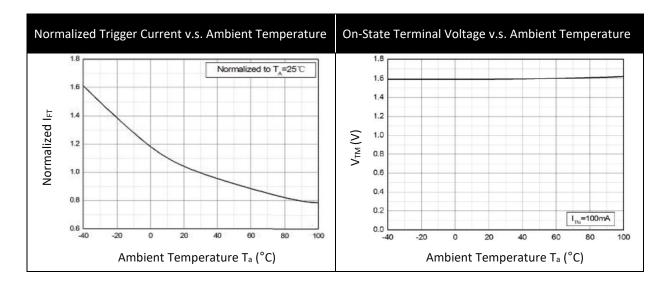


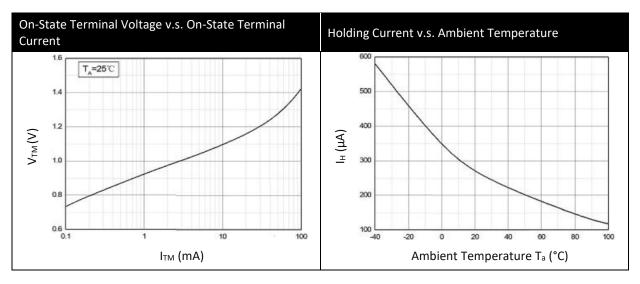


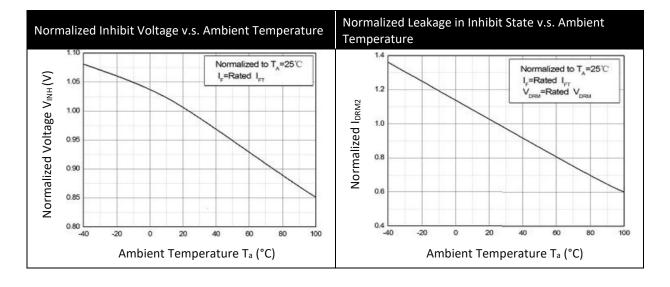




CHARACTERISTIC CURVES:

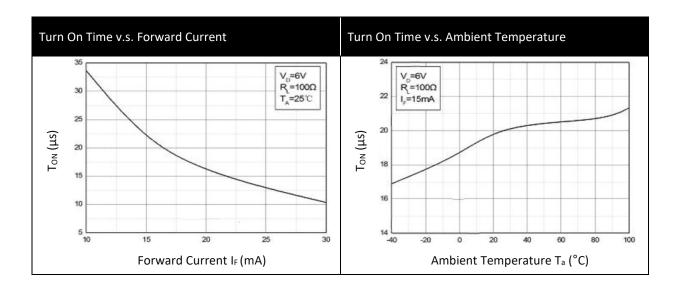








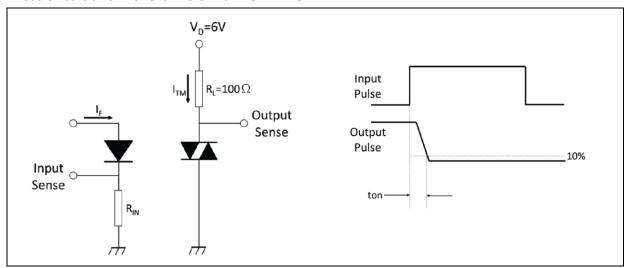
CHARACTERISTIC CURVES:



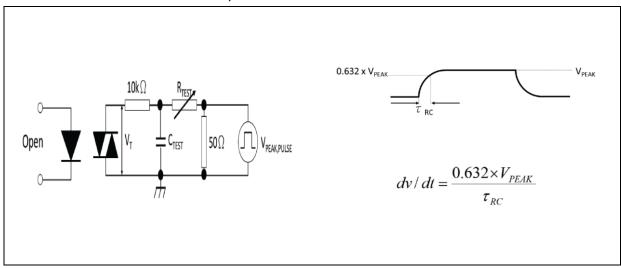


TEST CIRCUIT:

Test Circuit and Waveforms of Turn On Time:



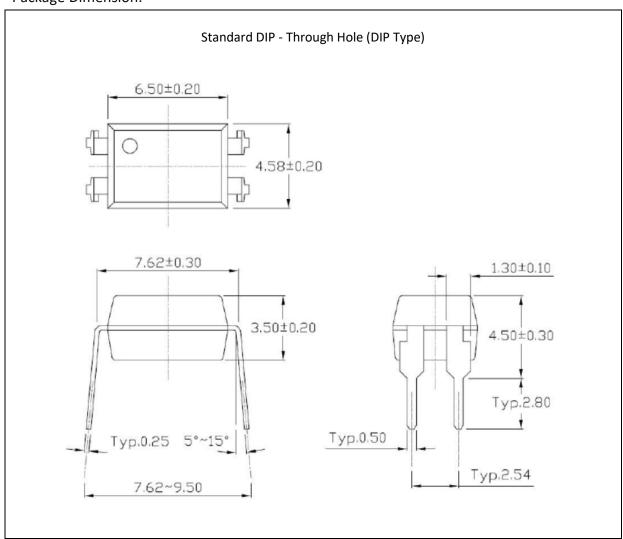
Test Circuit and Waveforms of dV/dt:





OUTLINE DIMENSION:

Package Dimension:

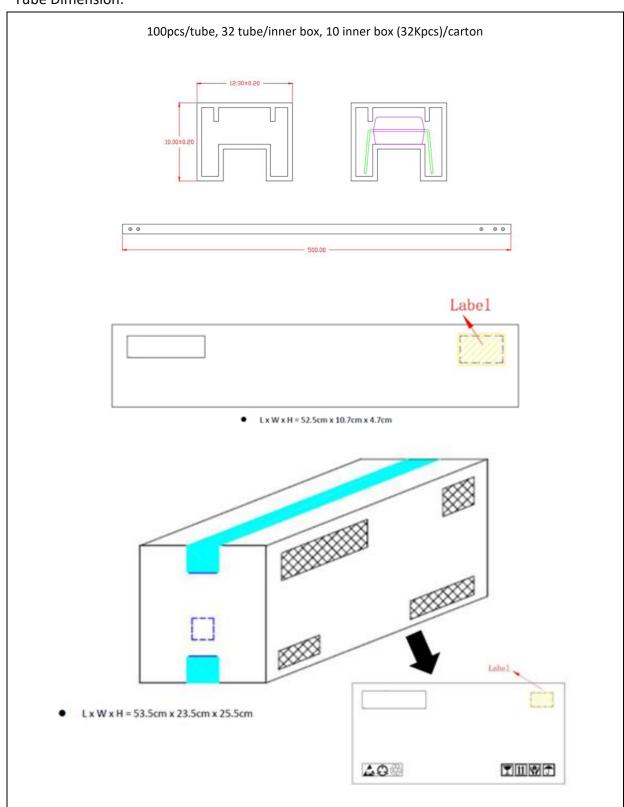


1. All dimensions are in millimetre (mm).



PACKING SPECIFICATION:

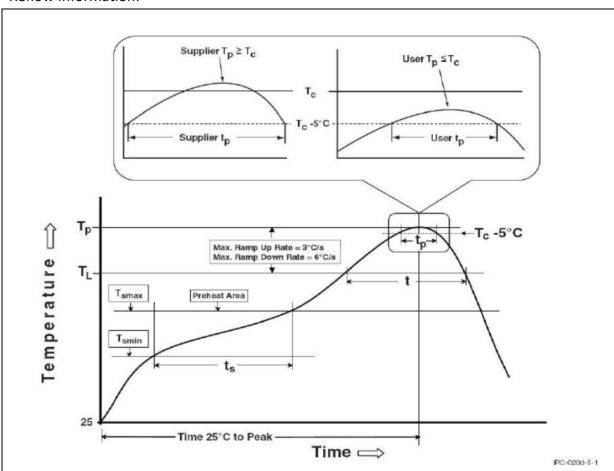
Tube Dimension:





RECOMMENDED SOLDERING PROFILE:

Reflow Information:

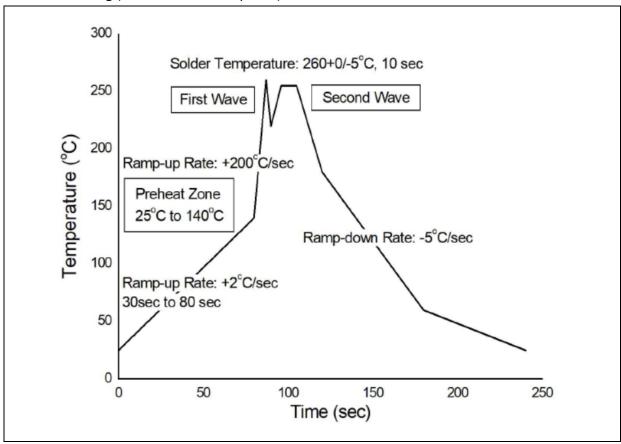


Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (T _{smin})	100°C	150°C
Temperature Max. (T _{smax})	150°C	200°C
Time (t _s) from (T _{smin} to T _{smax})	60-120 seconds	60-120 seconds
Ramp-up Rate (t₁ to t₂)	3°C/second max.	3°C/second max.
Liquidous Temperature (T _L)	183°C	217°C
Time (t _L) Maintained Above (T _L)	60-150 seconds	60-150 seconds
Peak Body Package Temperature	235°C +0°C / -5°C	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	20 seconds	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max.	6°C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.



RECOMMENDED SOLDERING PROFILE:

Wave Soldering (JESD22-A111 Compliant):



Hand Soldering:

Soldering Temperature	380±5°C
Soldering Time	3 sec max.

Note:

- One time soldering is recommended for all soldering methods.
- Do not solder more than three times for IR reflow soldering.